

MP5505 **7V, 4A, High-Efficiency Energy Storage and**

Management Unit

The Future of Analog IC Technology

DESCRIPTION

MP5505 is a lossless energy storage and management unit targeted at the solid-state and hard-disk drive applications. Its highly-integrated input-current limit and energy storage and release management makes the system solution very compact.

The internal input-current-limit block with dv/dt control prevents inrush current during system start up. The bus voltage start-up slew rate is programmable. It also includes a Power-On-Reset function for hot-swapping. MPS's patented energy storage and release management control circuit minimizes the storage capacitor requirement. It pumps the input voltage to a higher storage voltage and releases the energy over a hold-up time to the system in the case of an input outage. The storage voltage and the release voltage are both programmable for different system applications.

The MP5505 requires a minimal number of readily-available standard external components, and is available in a 20-pin QFN (3mm×4mm) package.

FEATURES

- Wide 2.7V-to-7V Operating Input Range
- Input Current Limiter with Integrated 60mΩ MOSFET
- Up to 4.5A Input Current Limit
- Reverse Current Protection
- 6V Bus Clamping Voltage
- Power-On-Reset
- Adjustable dv/dt Slew Rate for Bus Voltage Start-Up
- Internal 30mΩ Disconnect Switch
- Internal 70mΩ and 60mΩ Power Switches for Energy Storage and Release Management **Circuits**
- Thermal Protection
- EN and Power-Good Indicators
- Available in a QFN20 (3mm×4mm) Package

APPLICATIONS

- Solid-State Drives
- Hard-Disk Drives
- Power Back-up/Battery Hold-up Supplies

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MP5505 Rev. 1.01 www.MonolithicPower.com **1** MPS Proprietary Information. Patent Protected. Unauthorized Photocopy and Duplication Prohibited. © 2015 MPS. All Rights Reserved.

ORDERING INFORMATION Part Number* Package Top Marking MP5505GL QFN20L (3mmx4mm) MP5505 $*$ For Tape & Reel, add suffix $-Z$ (e.g. MP5505GL-Z); **PACKAGE REFERENCE TOP VIEW** 1 2 3 4 5 6 7 17 16 15 14 13 12 11 8 | 9 | 10 20| |19| |18 DVDT TPOR ILIM PGIN PGS EN **ENCH ICH** FBS FBB AGND **NC CST BST** VIN VB VBO PGND SW STRG **QFN20L (3mmx4mm)**

ABSOLUTE MAXIMUM RATINGS (1)

Recommended Operating Conditions **(3)**

Thermal Resistance **(4)** *θJA θJC* QFN20 (3mmx4mm) 48 10 ... °C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J $(MAX)-T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

 $V_{\text{in}} = 5.0V$, T_r = 25°C, unless otherwise noted.

ELECTRICAL CHARACTERISTICS *(continued)*

VIN = 5.0V, TA = 25°C, unless otherwise noted.

Notes:

5) VB UVLO is applied to Energy Storage and Release Circuitry

6) Guaranteed by design.

PIN FUNCTIONS

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OPERATION

The MP5505 is an energy storage and management unit in a 3mm×4mm 20-pin QFN package. It provides very compact and efficient energy management solution for a typical solidstate–drive or hard-disk–drive application. MPS's patented lossless energy storage and release management circuits use a bidirectional Buck/Boost converter to achieve optimal energy transfer and provide the most cost-effective energy storage solution.

The integrated boost converter raises the energy-storage voltage level. The storage feedback resistor divider sets the storage voltage. When the input suddenly shuts down, the internal Buck converter transfers the energy from the storage capacitor to the bus and keep holds the bus voltage when the system consumes the energy from the storage capacitor. The buck converter can work in 100% duty cycle operation to fully deplete the stored energy.

Start-Up

When VIN starts up, the bus voltage VB is charged from 0 to nearly VIN. The VB rising slew rate is controlled by DVDT capacitance. This function avoids the input inrush current and provides protection to the whole system.

EHCH is used to enable the storage charge and release circuitry. When ENCH is already high before VB finishing DVDT process, the storage charge circuitry will work automatically when VIN is higher than UVLO which is 2.5V typically.

The storage charge circuitry operates in two modes: the pre-charge mode where the STRG voltage is charged to VB voltage by using a current source and the boost mode where the STRG voltage is charged to finally setting voltage. The pre-charge mode charges the STRG voltage up to nearly VB voltage by using almost constant current source. The current is around 130mA. When STRG voltage is close to VB, and VB voltage is higher than certain threshold where the corresponding FBB is higher than 0.813V, the boost mode initiates.

The boost mode charges the STRG voltage to the target voltage finally. Figure 2 shows the charging build-up process when ENCH is high before VB starts up.

It is strongly recommended for our customers to enable the ENCH after VB is well settled down which is shown in Figure 3. Because the release mode is triggered when FBB voltage is lower than 0.79V, although there is a 23mV hysteresis between boost mode and release mode, in some high current charge boost mode case which can be programmed by ICH, VB voltage might be pulled low back and wrongly enter the release mode. In order to avoid this, the ENCH pin is suggested to be enabled after VB settling down. Figure 3 shows the charging build-up process when ENCH is enabled after VB settles down.

Storage Voltage

After the start up period, the internal Boost converter automatically regulates the storage voltage to a set value. The MP5505 uses burst mode to minimize the converter's power loss. When the storage voltage drops below the set voltage, burst mode initiates and charges the storage capacitor. During the burst period, the current limit and the low-side MOSFET control the switch. When the power MOSFET turns on, the inductor current increases until it reaches its current limit. The boost current limit can be programmable by ICH resistor. By default, it is around 500mA. After hitting the current limit, the power MOSFET turns off for the set minimum OFF time. At the end of this minimum OFF time, if the feedback voltage remains below the 0.79V internal reference, the power MOSFET turns on again; otherwise the MP5505 waits until the voltage drops below the threshold before turning on the MOSFET.

Release

The MP5505 continuously monitors the input and bus voltages. Once the bus voltage drops below the selected release voltage (such as when losing input power), the internal boost converter stops charging and works in buck release mode. In buck mode, the part transfers energy from the high-voltage storage capacitor to the low-voltage bus capacitor. Determine the release voltage by selecting resistor values for the bus resistor divider. The buck release current can be as high as 4.5A.

The released Buck applies the fixed-frequency constant-on-time (COT) enables the fast transition between charge and release modes. The buck converter works at 100% duty cycle until the storage capacitor voltage approaches the bus voltage. Then the storage and bus voltages drop until they reach the DC-DC converterís UVLO, as shown in Figure 4.

Input-Current Limit

The input-current limiter carefully controls the input inrush current of the internal hot-swap MOSFET to prevent an inrush current from the input to the bus. A capacitor connected to dv/dt pin can set the soft-start time. Despite of the soft-start process, the ILIM pin can also limit the steady-state current. Connect a resistor between ILIM and GND to set the current limit.

Reverse-Current Protection

The hot-swapping circuit uses reverse-current protection to prevent the storage energy from transferring back to the input during energy released from storage capacitors to bus. The hot-swapping MOSFET turns on when input voltage exceeds the VIN UVLO threshold during start up, and turn off when input voltage falls below the bus voltage during release.

Start-Up Sequencing

Connect a capacitor across the DVDT pin to program the soft-start time. During soft-start, the energy storage capacitors charge. Very short dv/dt times can trigger the current-limit threshold. Select the DVDT capacitor based on the storage capacity.

Storage Power-Good Indicator, PG_S

When the voltage on the FBS pin (storage feedback) drops below $0.9 \times V_{FBS}$, the MP5505 internally pulls the storage PGS pin LOW. When the FBS voltage is above $0.95 \times V_{FBS}$, this pin goes HIGH.

Bus Power-Good Indicator, PG_{IN}

When the voltage on FBB pin (bus feedback) falls below $1.0 \times V_{FBB}$, the MP5505 pulls PG_{IN} LOW to indicate releasing status. When MP5505 works in Boost mode, the PG_{IN} will be pulled high to indicate charging status.

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APPLICATION INFORMATION

Setting the Storage Voltage

Set the storage voltage by choosing the external feedback resistors R1 and R2 shown in Figure 5.

Figure 5: Storage Feedback Circuit

The storage voltage is determined by:

$$
V_{\text{STORAGE}} = (1 + \frac{R1}{R2}) \times V_{\text{FBS}}
$$

Where V_{FBS} is 0.79V typically. R1 and R2 are not critical for normal operation. Select R1 and R2 higher than 10kΩ to account for the bleed current. For example, if R2 is 14kΩ, R1 is then:

$$
R1 = \frac{14k\Omega \times (V_{\text{STORAGE}} - V_{\text{FBS}})}{V_{\text{FBS}}}
$$

For a 12V storage voltage, R1 is 200kΩ.

Table 1 lists the recommended resistors for different storage voltages.

Select Release Voltage and Input Capacitors

Select the release voltage by choosing the external feedback resistors R3 and R4 as shown in Figure 6.

Similarly, the release voltage is:

$$
V_{RELEASE} = (1 + \frac{R3}{R4}) \times V_{FBB}
$$

 V_{FBB} is also 0.79V typically. However, R3 and R4 not only determine the release voltage, but affect stability. Since the release buck mode works in COT mode, avoid

small resistor values to ensure a sufficient voltage ramp. Generally, choose R3//R4≥20kΩ for stable performance with $C_B=22\mu F$. Table 2 lists the recommended resistor values for different release voltages.

Figure 6: Release Feedback Circuit

Table 2: Resistor Pairs for VRELEASE

Selecting the Storage Capacitor

The storage capacitor stores energy during normal operation and releases this energy to VIN when VIN loses input power. Use a generalpurpose electrolytic capacitor or low profile POS capacitor for most applications.

Select a storage capacitor with a voltage rating that exceeds the targeted storage voltage. The stable voltage on the storage capacitor during normal operation allows for full capacitor utilization. Consider the capacitance reduce with the DC voltage offset when choosing the capacitors. Different capacitors have different capacitance derating performance. Choose capacitor with enough voltage rating to guarantee enough capacitance.

The required capacitance depends on the length of the "dying gasp" for a typically application. Assume the input release current is $I_{RELEASE}$ when input voltage is regulated at $V_{RELEASE}$ for the DC-DC converter, the storage is $V_{STORAGE}$, and the required dying gasp time is T_{DASP} . The required storage capacitance is then:

$$
C_{\rm S} = \frac{2 \times V_{\rm RELEASE} \times I_{\rm RELEASE} \times \tau_{\rm DASP}}{V_{\rm STORAGE}^2 - V_{\rm RELEASE}^2}
$$

Consider of the power loss during releasing where the Buck converter can run up to 90% efficiency in most application, select storage capacitance to 1.1xCs to ensure enough releasing time. If $I_{RELEASE}$ =1A, τ_{DASP} =20ms, $V_{STORAGE}$ =12V, $V_{RFIERSE}$ =4.2V, then the required storage capacitance is 1500μF.

For typical applications using a 5V input supply, set the storage voltage above 10V to fully utilize the high-voltage energy and minimize the storage capacitance requirements. Generally, use the 16V POS capacitor or 25V electrolytic capacitors.

Selecting the External Diode

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The external diode is strongly recommended for normal operation of charge mode where the boost converter works. The voltage rating should be higher than the storage voltage and the current rating should be high than the current programmed by ICH pin.

Setting the Input Hot-Swap Current Limit

Connect a resistor from ILIM to GND to set the current limit value. For example, a 1.2kΩ resistor sets the current limit to about 4.1A. Table 3 lists the recommended resistors for different current limit values.

Selecting Inductor

The inductor is necessary to supply constant current to the load. Since the Boost mode and Buck mode are sharing the same inductor, and generally the Buck mode current is higher, the inductor supporting at least the Buck mode releasing current is recommended.

Selecting the inductor based on Buck releasing mode. If the storage voltage is VS, the release voltage is VR, and Buck running at fixed 500kHz frequency. The inductance value can be calculated by:

$$
L = \frac{V_R}{\Delta l_L \times F_{\text{SW}}} \times (1 - \frac{V_R}{V_s})
$$

Where ΔI_L is the peak to peak inductor ripple current which can be set in the range of 30% to 40% of full releasing current.

The inductor should not saturate under the maximum inductor peak current.

Setting the Power-On Reset Delay Time

Connect a capacitor to the TPOR pin to set the power on reset delay time. Leave it floating for the default delay time of around 0.4ms. Table 4 lists the recommended capacitors for different delay times. In order to eliminate the power on reset delay, connect the TPOR pin directly to VIN.

Table 4: Reset Delay vs. Capacitor Value

Setting the Bus Voltage Rise Time

Connect a capacitor to the DVDT to set the bus voltage start-up slew rate and soft-start time. Leave it floating for the default soft start time of around 0.9ms from 0V to 5V. Table 5 lists the recommended capacitors for different soft-start times.

Table 5: Soft-Start vs. Capacitor Value

Layout Recommendation

- 1) The high current paths (VIN, VB, VBO, SW, STRG, GND) should use short, wide and direct traces.
- 2) Put the decoupling capacitor across VB and GND as close as possible.
- 3) Put the decoupling capacitor across STRG and GND as close as possible.
- 4) Keep the switching node SW short and away from the feedback network.
- 5) The external feedback resistors should be placed next to FB pins.
- 6) Keep the BST voltage path (BST, C6, R5 and SW) as short as possible.
- 7) Four-layout is recommended to achieve better thermal performance and easily layout.

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Design Example

Below is a design example following the application guidelines for the specifications:

Table 6: Design Example

The detailed application schematic is shown in Figure 8. The typical performance and circuit waveforms have been shown in the Typical Performance Characteristics section. For more device applications, please refer to the related Evaluation Board Datasheets.

Figure 8: Detailed Application Schematic

PACKAGE INFORMATION

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